# K ondo resonance enhanced supercurrent in single wall carbon nanotube Josephson junctions

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# Abstract

We have contacted single wall carbon nanotubes grown by chem ical vapor deposition to superconducting T i/A l/T i electrodes. The device, we here report on is in the K ondo regime exhibiting a four-fold shell structure, where a clear signature of the superconducting electrodes is observed below the critical temperature. Multiple Andreev re ections are revealed by sub-gap structure and a narrow peak in the di erential conductance around zero bias is seen depending on the shell lling. We interpret the peak as a proximity induced supercurrent and examine its interplay with K ondo resonances.

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# I. IN TRODUCTION

Single wall carbon nanotubes (SW CNT) have been under intense investigation for more than a decade due to their unique mechanical and electrical properties. They are onedimensional conductors with two conducting modes and when contacted to electrodes they behave as quantum dots, where phenom ena as Fabry-Perot interference [1], K ondo e ect [2] and Coulom b blockade [3, 4] have been observed. The di erent regimes can be accessed by indirectly controlling the coupling between the SW CNT and the contacts by choice of contact material. In the low transparency regime (closed quantum dot), electron transport is blocked except at charge degeneracy points, where electrons can tunnel through the SW CNT only one by one due to Coulomb blockade. W hen the transparency is increased (interm ediate regime) cotunneling of electrons becom es possible, which can give rise to the K ondo e ect. Finally in the high transparency regime electrons on the SW CNT are not well de ned and the phenom ena observed (broad resonances) are due to interference of electron waves (Fabry-Perot interference). The possibility of contacting carbon nanotubes to superconducting leads [5, 6, 7, 8] opens up for the interesting study of e ects related to superconductivity such as supercurrent and multiple Andreev re ections [9] together with the above mentioned phenom ena. In the Fabry-Perot regim e recent experim ents have con m ed that the supercurrent is modulated by the quantized nature of the energy spectrum of the SW CNT, i.e., a Josephson eld e ect transistor with only two modes [10, 11]. Experimental access to the less transparent regimes [12, 13, 14, 15] is even more interesting due to the possibility of probing the competition between e ects related to C oulom b blockade and superconductivity. C oulom b blockade generally suppresses the supercurrent and interesting phenom ena such as

-junction behavior has been observed in the closed quantum dot regime in nanowires [14]. For more transparent devices the supercurrent can be enhanced due to K ondo physics [16]. Both supercurrent and K ondo physics are two extensively studied manybody elects in condensed matter physics and SW CNT Josephson junctions thus give a unique possibility to exam ine their interplay. The supercurrent is predicted to coexist with K ondo resonances provided that the K ondo related energy scale  $k_B T_K$  is bigger than the superconducting energy gap [16, 17, 18]. The importance of the ratio between these parameters has recently been addressed in dilerent measurements [19]. In this article we extend this investigation to SW CNTs contacted to superconducting leads in order to experimentally probe the interplay between supercurrent and K ondo physics. We investigate the gate dependence of a narrow zero bias conductance peak interpreted as a proximity induced supercurrent and show that the observation of a supercurrent in K ondo resonances depends on the ratio between the two energy scales ( $k_B T_K =$ ) with a crossover close to 1 qualitatively consistent with theory.

#### II. EXPERIMENTAL DETAILS

SW CNTs are grown from catalyst islands consisting of Fe-oxide and M o-oxide supported by alum inum nano-particles [20]. Growth is performed by chemical vapor deposition at 850 C with a controlled ow of gasses Ar: 1L/m in, H<sub>2</sub>:0:1L/m in, CH<sub>4</sub>:0.5L/m in. During heating the furnace is kept under an Ar and  $H_2$  ow, whereas cooling is done in Ar. We reduce cooling time by air-cooling the furnace. The substrate is a doped silicon wafer (used as back gate) with a 500 nm SiO<sub>2</sub> layer on top. Pairs of superconducting electrodes of Ti/A l/Ti (5/40/5 nm) are de ned directly on top of the SW CNT by electron beam lithography followed by optical lithography to de ne the Cr/Au bonding pads. The rst titanium layer of the m etallic trilayer ensures good contact to the SW CNT, whereas the thicker middle alum inum layer is the actual superconductor in the device. Finally, the top layer of T i is intended to stop oxidation of the alum inum. The gap between the source and drain electrode is typically around 0.5 m. In the same evaporation process a four-probe device is made next to the S-SW CNT-S devices, which is used to measure the transition temperature  $T_c$  = 760 mK and the critical eld around  $B_c = 100 \text{ mT}$  of the superconductor. From Bardeen-Cooper-Schrie er (BCS) theory we deduce the superconducting energy gap =  $1.75k_BT_c =$ 115 eV. The devices are cooled in a  ${}^{3}\text{H}e^{-4}\text{H}e$  dilution fridge with a base tem perature around 30 m K and we use standard lock-in techniques.

# III. SUB-GAP STRUCTURE AND SUPERCURRENT

At room temperature the current through the device is gate dependent, which reveals that the SW CNT is sem iconducting. Figure 1 (a) shows a bias spectroscopy plot at 30 m K of the SW CNT device in the K ondo regime. It is measured at negative gate voltages and thus transport takes place through the valence band, i.e., tunneling of holes. The superconductivity in the leads is suppressed by a relative weak magnetic eld of 180 m T (> B<sub>c</sub>).

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FIG.1: (a) Bias spectroscopy plot of a SW CNT device at 30 m K showing a four-fold C oulom b blockade shell structure. The numbers indicate the additional hole lling, where big diam onds correspond to lled shells. Four K ondo resonances K1-K4 are identied. A magnetic eld of 180 m T is applied to suppress superconductivity in the leads. (b) Bias spectroscopy plot for the sam e gate range as (a) but with the leads in the superconducting state. A sub-gap structure emerges, most clearly visible at =e and 2 =e (horizontal green dashed lines). The green dashed rectangles are the gate voltage regions shown in Fig.2(c) and 2(d).

The plot show s C oulom b blockade diam onds [21] with a characteristic pattern of three sm all diam onds followed by a bigger diam ond as indicated with white lines for hole lling 13-16. Such C oulom b blockade diam ond structure indicates a four-fold degenerate shell structure due to spin and orbital degrees of freedom, where each shell contains two spin-degenerate orbitals [22]. The lled shells corresponding to the big C oulom b blockade diam onds are m arked in F ig. 1 (a) by the additional num ber of holes on the SW CNT quantum dot. D ue to interm ediate transparency contacts signi cant cotunneling is allowed which tends to sm ear the features. The charging energy and the level spacing between the shells are estim ated as half the source-drain height of the very faintly visible sm all diam onds and by the additional structure is the source-drain height of the very faintly visible sm all diam onds and by the additional structure is a shalf the source-drain height of the very faintly visible sm all diam onds and by the additional structure is the structure is a shalf the source-drain height of the very faintly visible sm all diam onds and by the additional structure is the structure of the structure is a structure of the structure is a structure of the very faintly visible sm all diam onds and by the additional structure is the structure.

tional source-drain height of the big diam onds [23] giving  $U_c$  3 meV and E 4 m eV, respectively (see arrows Fig. 1). A very rough estimate of the level broadening 1meV and the asymmetry in the coupling to source and drain = s = d0:4 are extracted from the current plateaus at negative and positive bias (100 nA and -60 nA) at the white arrows. The current is modied due to the four-fold degeneracy which enhances the intunneling rate with 4 compared to the out-tunneling rate giving (=h)4 s d=(4 s+ d) and (e=h) (4 d s=(s+4 d) for negative and positive bias polarity, respectively [24]. Furthermore, four K ondo resonances K 1-K 4 are identied (green arrows) and labeled in ascending order based on their K ondo tem peratures. The K ondo tem peratures are estim ated by tting the norm all state conductance versus  $V_{sd}$  (solid line in Fig. 3a-b) to a Lorentzian line shape. The halfwidth at halfmaximum of each Lorentzian tyields the estimated K ondo tem per-2K, 4.5K, 5K and 6K for K1-K4. For hole lling 13-15, conductance ature giving  $T_{K}$ ridges at low nite bias are seen instead of zero bias K ondo resonances. The exact origin of these features are not fully understood, but they are attributed to inelastic cotunneling through two slightly split orbitals in the shell, which might include K ondo physics as well [25]. We note that these lines are not related to superconductivity.

Figure 1 (b) shows a bias spectroscopy plot at low bias voltages for the same gate range as Fig. 1 (a) with the leads in the superconducting state. A sub-gap structure clearly appears [9]. The peaks in di erential conductance at  $V_{sd} = 2 = 2$  230 V are attributed to the onset of quasi-particle tunneling. At lower bias the transport is governed by Andreev re ections, which are possible due to the interm ediate transparency between the SW CN T and the superconducting leads [26]. Features at biases  $V_n = 2 = (en); n = 2; 3; ... are$ expected due to the opening of higher order multiple Andreev re ection processes as the $bias is lowered [27, 28]. Peaks at <math>V_{sd} = = 115$  V are clearly seen consistent with the energy gap found from BCS theory. Furtherm ore, for some ranges in gate voltage a narrow zero bias conductance peak is seen. W e note, that this zero bias peak is visible in m ost of the K ondo resonances and is the subject to analysis below.

These above mentioned e ects due to superconductivity are more clearly revealed in high resolution data shown in Fig. 2 (c) and 2 (d) corresponding to the green dashed rectangles in Fig. 1 (b). Figure 2 (a) and 2 (b) show the same gate and bias regions as (c) and (d) with the leads in the norm all state for comparison. C learly the sub-gap structure is due to the proximity of the superconducting leads. The peaks at 2 = e and = e are mostly

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FIG. 2: (a-b) B ias spectroscopy plot at 30 m K with the leads in the norm al state (B = 180 m T) for K ondo resonance K 4 and K 1, respectively. (c-d) H igh resolution data with the leads superconducting for the same gate and bias voltages as in the norm al state above. The corresponding gate regions are shown by the dashed green rectangles in Fig. 1 (b). A sub-gap structure appears at bias voltage 2 =e and =e indicated by the green dashed lines. This is particular clear in the C oulom b blockade region (d) and also seen in the green traces, which are dI=dV versus bias curves extracted from the plots. A zero bias conductance peak (red arrow) is also visible throughout K ondo resonance K 4 as shown by the red trace in (d) and for some gate voltages in (c).

pronounced in the C oulom b blockade region as expected due to lower e ective transparency [27] (d) while being m one sm eared in the high conducting region of K 4 (c). G meen curves show bias cuts, where higher order multiple Andreev rejection features are faintly visible in (c). A strong gate dependence of the sub-gap structure is observed when the gate voltage is tuned closer to the C oulom b resonances on each side of K 1 from the C oulom b diam ond with even occupation. This behavior has previously been observed [9] and explained by the interplay between multiple Andreev rejection and a resonant level [29, 30]. The zero bias conductance peak indicated by the red arrow is clearly visible in K ondo resonance K 4 (red trace in (c)) and also present for some gate voltages in (d). Sim ilar behavior of a zero bias peak in K ondo

resonances have been observed in other devices [13]. We interpret the zero bias conductance peak as being due to a proximity induced supercurrent running through the SW CNT. The m agnitude of the supercurrent is estim ated by the area of the peak giving a typical value in the order of Im 02 nA.A sim ilar analysis of a zero bias conductance peak as supercurrent has successfully been carried out for an open quantum dot [11], i.e., without Coulomb blockade e ects. We note that an alternative interpretation of the origin of the zero bias peak based on quasiparticle current (multiple Andreev re ections) with a cut-o for higher order multiple Andreev re ection processes has also been suggested [31], but in this article the supercurrent interpretation will be pursued. The value of the measured supercurrent is highly suppressed compared to its theoretically expected value for one spin-degenerate level with the deduced asymmetric coupling (=0.4) at resonance  $I_0^{res} = 2e = h (_{min} = )$ 8nA in the broad resonance (short) regime > , where  $m_{in} = m_{in} (s; d)$ 03meV 32]. Despite having two spin-degenerate levels in the SW CNT, only one level is available due to Coulomb blockade.

The suppression is partly explained within an extended resistively and capacitively shunted junction model due to interaction of the SW CNT Josephson junction with its electrical environment. The electrical environment for this device is the low (serial) resistance between the Josephson junction and the bonding pads as well as the capacitance between the source and drain bonding pads via the backgate. The low serial resistance turns out to play a crucial role making the device an underdam ped Josephson junction [10, 11, 33, 34]. This means that the full value of the critical current is never measured due to therm ally activated phase slips. A more intuitive understanding is obtained by the mechanical analog to the Josephson junction of a ctious particle in a tilted washboard potential, where the tilt is given by the current and the phase di erence between the superconductors is "running" as the ctious particle moves in the potential. W hen the particle stays in a minimum of the washboard potential (constant phase), a supercurrent is seen. However, as the current increases the washboard potential is tilted and at the critical current the particle can slide into the next m inim um. If therm all excitations are significant this process happens at lower current than the critical current. Since the junction is underdam ped, the friction of the particle is low and it thus easily acquires a "run away" phase, that suppresses the supercurrent, which results in a much lower measured supercurrent. In contrast to the reported underdam ped carbon nanotube Josephson junction in the Fabry-Perot regime [11], the e ect of

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FIG. 3: dI=dV versus  $V_{sd}$  for K ondo resonances K 1-K 4 shown in Fig. 1 (a) illustrating the e ect of superconducting leads. (a-b) Solid lines and circles are with the leads in the norm al and superconducting state, respectively. (c) The four K ondo resonances K 1-K 4 for sm all bias voltages with the leads in the superconducting state. The measured supercurrent given by the zero bias peak area is zero for the lowest value of the ratio  $k_B T_K =$ , while it increases as this ratio is increased.

C oulom b blockade and single hole tunneling also contribute to the suppression of the supercurrent, because C ooper pair transport is a two particle tunneling process. A quantitative analysis of the suppression due to C oulom b blockade is outside the scope of this article. This issue is being addressed in a separate work, where the on-chip electrical circuit of the SW CNT Josephson junction has been m odi ed and the elects of C oulom b blockade thus can be compared to theoretical calculations [35]. Finally, we note that noise elects giving rise to therm ally activated phase slips can be analyzed in the overdam ped case [36].

# IV. KONDO PHYSICS AND SUPERCURRENT

W e now return to the K ondo resonances K 1-K 4 and analyze the interplay between K ondo physics and supercurrent. The solid curves in F ig. 3 (a) and 3 (b) show bias cuts with the leads in the norm all state through the center of K ondo resonance K 2 and K 4, respectively (see F ig. 1 (a)). The circles correspond to the behavior when the leads are superconducting. In both cases an enhancem ent of the di erential conductance is observed for bias voltages between



FIG. 4: (a) The measured supercurrent is zero for K1 and shown to increase as a function of  $k_B T_K = (K 1 - K 4)$ . An exponential t to the data points is given by the solid curve as guideline, where the K ondo temperature is based on the width of the resonance (black diam onds). The red squares are the K ondo temperature obtained from the temperature dependence (K 1, K 3 and K 4). (b) M easured supercurrent versus gate voltage in the range with the K ondo resonances K 1-K 4, where the additional hole number is given for lled shells as in Fig. 1 (a). A nite supercurrent is seen in the center of the broader K ondo resonance K 2, while being zero in the center of narrow est K ondo resonance K 1. This behavior does not relect the norm al state conductance G N shown for the same gate range below in (c).

2 =e and a zero bias conductance peak is present due to supercurrent. The measured supercurrent is largest for the K ondo resonance with the highest K ondo tem perature (K 4), i.e., broadest K ondo resonance. In Fig. 3 (c) bias sweeps at the center of all four K ondo resonances are shown with the leads in the superconducting state. The K ondo tem perature norm alized by the superconducting energy gap ( $k_B T_K = 1$ ) is the important parameter and is given for each resonance in the gure. It is seen that the measured supercurrent vanishes for the lowest ratio (blue circles) while it emerges and increases as the ratio is increased. The crossover is close to  $k_B T_K = 1$ .

To illustrate this point m ore clearly, the m easured supercurrent versus  $k_B T_K =$  is plotted in F ig. 4 (a) for the four K ondo resonances analyzed above (black diam onds). The solid curve shows a guideline to the eye based on an exponential t to the available data points. The overall trend is qualitative consistent with existing theory, which predicts a suppression of the supercurrent in the socalled weak coupling regime ( $k_B T_K$  ), while the supercurrent coexists with K ondo resonances in the strong coupling regime ( $k_B T_K$  ) [17, 18]. The red squares show the measured supercurrent where the K ondo temperature is extracted from the temperature dependence for completeness (only data available for K 1, K 3 and K 4) [37].

F inally, F ig. 4 (b) shows the measured supercurrent as a function of gate voltage in the range including the four K ondo resonances. It is strongly gate dependent illustrating e ects of the four K ondo resonances. Figure 4 (c) shows the zero bias conductance  $G_N$  with the leads in the norm al state for the sam e gate range. The supercurrent does not directly re ect the norm al state conductance  $G_N$  as in the case of an open quantum dot [10, 11], where the supercurrent is uniquely determ ined by the norm al state conductance. This is most clearly seen by comparing K ondo resonance K1 and K2. No supercurrent is present in the center of the K ondo resonance K 1 despite the high norm al state conductance, while a nite supercurrent is present in K ondo resonance K 2 with equally high norm al state conductance in contrast to the behavior expected in the open quantum dot regime. Similarly, the K ondo resonances K 3 and K 4 have alm ost the sam e norm al state conductances, but very di erent m easured supercurrent. These observations support the above analysis that the interplay between K ondo physics and superconductivity has the fraction  $k_B T_K = as$  the important param eter for the observation of supercurrent in K ondo resonances, i.e., the bias width of the K ondo resonances and not only their norm al state conductance is in portant. We also note that the measured supercurrent in diam ond 4,8 and 12 is zero due to Coulomb blockade. The supercurrent in the high  $T_K$  K ondo resonances can thus be view as being enhanced from the suppressed values by Coulomb blockade and the single spin due to the form ation of K ondo resonances. Furtherm ore, the overall behavior of the supercurrent of these four K ondo resonances also indirectly indicates a to 0 transition of the current phase relation of the Josephson junction as a function of the parameter  $k_{\rm B} T_{\rm K} = [17, 18]$ . Sim ilar gate voltage behavior has been observed in Ref. [15], but the authors do not show the magnitude of the supercurrent as a function of K ondo tem perature. W e end by noting that for large K ondo tem peratures com pared to the superconducting energy gap (K 4), the observed gate voltage dependence of the supercurrent resembles the behavior of a superconducting single electron transistor, i.e., the supercurrent obtains a sharp maximum at the gate voltage corresponding to the center of the odd diam ond [38].

# V. CONCLUSION

In conclusion SW CNTs have been contacted to superconducting T i/A l/T i leads creating SW CNT Josephson junctions. We observe sub-gap structure due to multiple Andreev reections and a narrow zero bias conductance peak. The zero bias peak is interpreted as a proximity induced supercurrent with a suppressed magnitude due to the underdam ped nature of the Josephson junction and C oulom b blockade. We exam ineits interplay with K ondo resonances and the measured supercurrent is shown to coexist with K ondo resonances which have high K ondo temperatures compared to the superconducting energy gap, while being suppressed when the K ondo temperatures becomes comparable with the superconducting energy gap, qualitative consistent with existing theory.

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